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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

KA5x0165Rxx-SERIES

KA5H0165R/RN, KA5M0165R/RN, KA5L0165R/RN, KA5H0165RVN
Fairchild Power Switch(FPS)

Features

- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current (Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
  - except KA5H0165RVN
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry compared to discrete MOSFET and controller or R_{CC} switching converter solution, The Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It is well suited for cost effective design of flyback converters.

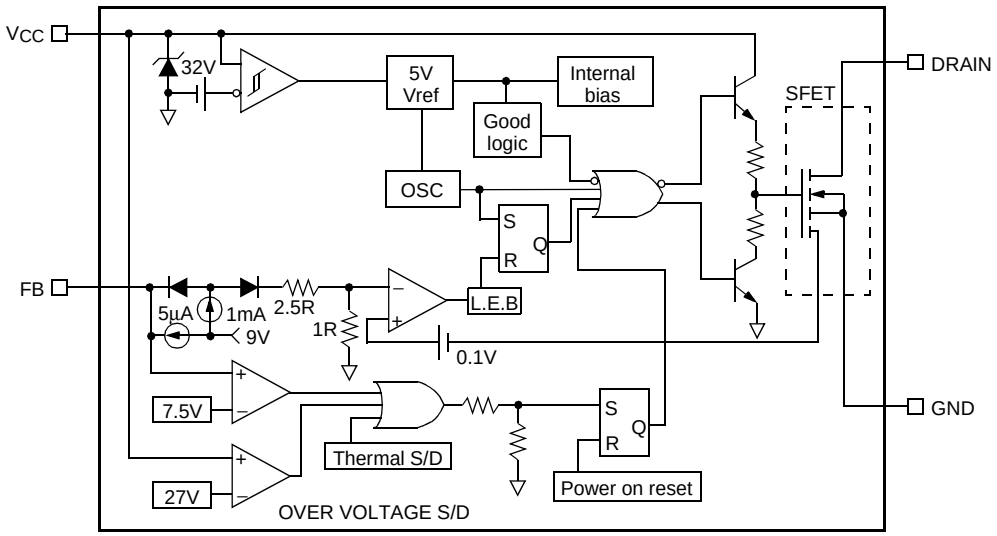
TO-220F-4L

1. GND
2. Drain
3. Vcc
4. FB

8-DIP

1.6.7.8. Drain
2. GND
3. Vcc
4. FB
5. NC

Internal Block Diagram



Rev.1.0.5

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Drain-Gate Voltage (R_{GS}=1MΩ)	V_{DGR}	650	V
Gate-Source (GND) Voltage	V_{GS}	±30	V
Drain Current Pulsed (1)	I_{DM}	4.0	A_{DC}
Continuous Drain Current (T_C=25°C)	I_D	1.0	A_{DC}
Continuous Drain Current (T_C=100°C)	I_D	0.7	A_{DC}
Single Pulsed Avalanche Energy (2)	E_{AS}	95	mJ
Maximum Supply Voltage	$V_{CC,MAX}$	30	V
Analog Input Voltage Range	V_{FB}	-0.3 to V_{SD}	V
Total Power Dissipation	P_D	40	W
	Derating	0.32	W/°C
Operating Junction Temperature.	T_J	+160	°C
Operating Ambient Temperature.	T_A	-25 to +85	°C
Storage Temperature Range.	T_{STG}	-55 to +150	°C

Note:

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L=24mH, starting Tj=25°C

Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=50μA	650	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=Max. Rating, V_{GS}=0V	-	-	50	μA
		V_{DS}=0.8Max. Rating, V_{GS}=0V, T_C=125°C	-	-	200	μA
Static Drain-Source on Resistance (Note)	$R_{DS(ON)}$	V_{GS}=10V, I_D=0.5A	-	8	10	Ω
Forward Transconductance (Note)	gfs	V_{DS}=50V, I_D=0.5A	0.5	-	-	S
Input Capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	250	-	pF
Output Capacitance	Coss		-	25	-	
Reverse Transfer Capacitance	Crss		-	10	-	
Turn on Delay Time	td(on)	V_{DD}=0.5B V_{DSS}, I_D=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	12	-	nS
Rise Time	tr		-	4	-	
Turn Off Delay Time	td(off)		-	30	-	
Fall Time	tf		-	10	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V_{GS}=10V, I_D=1.0A, V_{DS}=0.5B V_{DSS} (MOSFET switching time is essentially independent of operating temperature)	-	-	21	nC
Gate-Source Charge	Qgs		-	3	-	
Gate-Drain (Miller) Charge	Qgd		-	9	-	

Note:

1. Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%
2. $S = \frac{1}{R}$

Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	V_{START}	V_{FB}=GND	14	15	16	V
Stop Threshold Voltage	V_{STOP}	V_{FB}=GND	8.2	8.8	9.4	V
OSCILLATOR SECTION						
Initial Accuracy	F_{OSC}	**KA5H0165Rxx**	90	100	110	kHz
Initial Accuracy	F_{OSC}	**KA5M0165Rx**	61	67	73	kHz
Initial Accuracy	F_{OSC}	**KA5L0165Rx**	45	50	55	kHz
Frequency Change With Temperature (2)	$\Delta F/\Delta T$	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum Duty Cycle	Dmax	**KA5H0165Rxx**	62	67	72	%
Maximum Duty Cycle	Dmax	**KA5M0165Rx** **KA5L0165Rx**	72	77	82	%
FEEDBACK SECTION						
Feedback Source Current	I_{FB}	Ta=25°C, 0V ≤ Vfb ≤ 3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V_{SD}	Vfb ≥ 6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	Idelay	Ta=25°C, 3V ≤ Vfb ≤ V_{SD}	4	5	6	µA
REFERENCE SECTION						
Output Voltage (1)	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability (1)(2)	Vref/ΔT	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT(SELF-PROTECTION)SECTION						
Peak Current Limit	I_{OVER}	Max. inductor current	0.53	0.6	0.67	A
PROTECTION SECTION						
Thermal Shutdown Temperature (1)	T_{SD}	-	140	160	-	°C
Over Voltage Protection	V_{OVP}	except **KA5H0165RVN**	25	27	29	V
TOTAL STANDBY CURRENT SECTION						
Start-up Current	I_{START}	V_{CC}=14V	-	100	170	µA
Operating Supply Current (Control Part Only)	I_{OP}	V_{CC} ≤ 28	-	7	12	mA

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

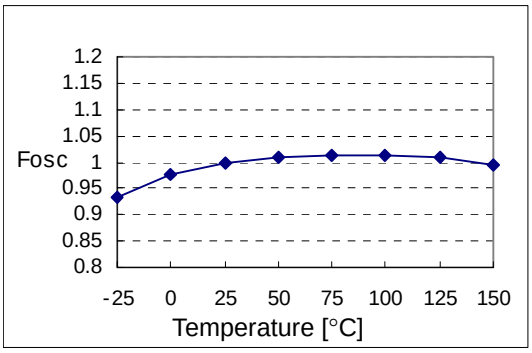


Figure 1. Operating Frequency

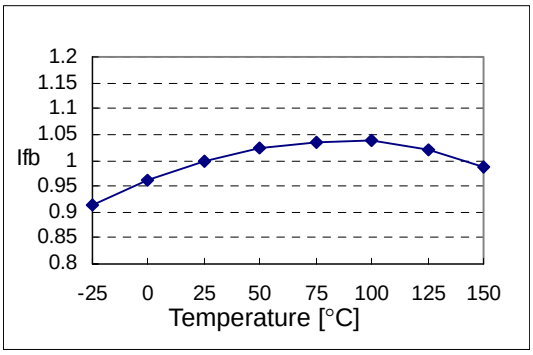


Figure 2. Feedback Source Current

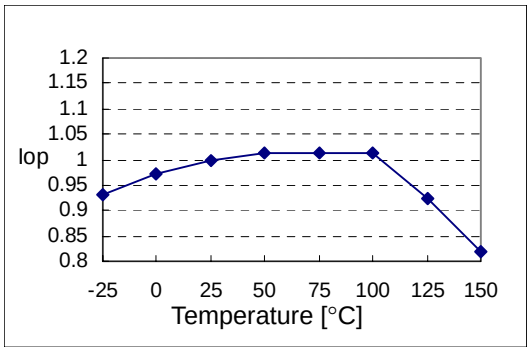


Figure 3. Operating Supply Current

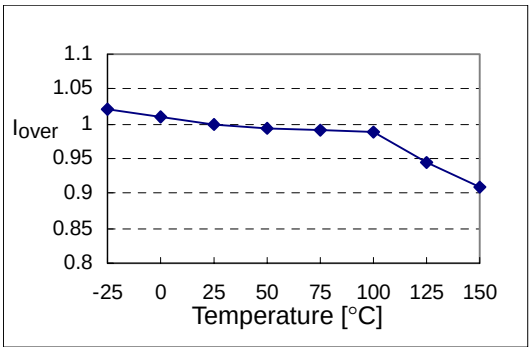


Figure 4. Peak Current Limit

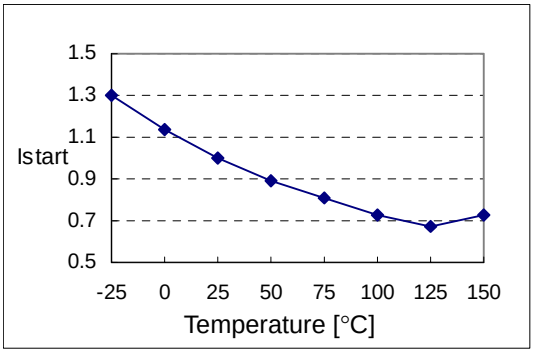


Figure 5. Start up Current

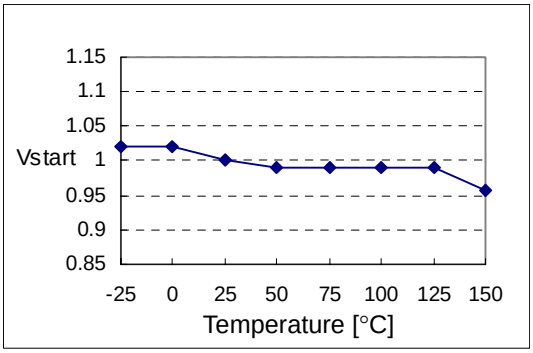


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

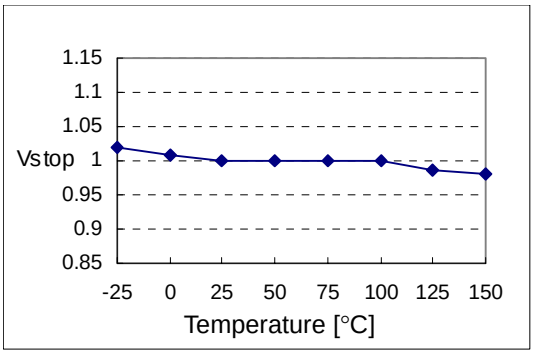


Figure 7. Stop Threshold Voltage

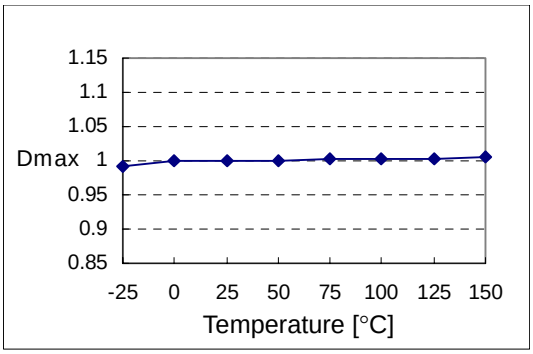


Figure 8. Maximum Duty Cycle

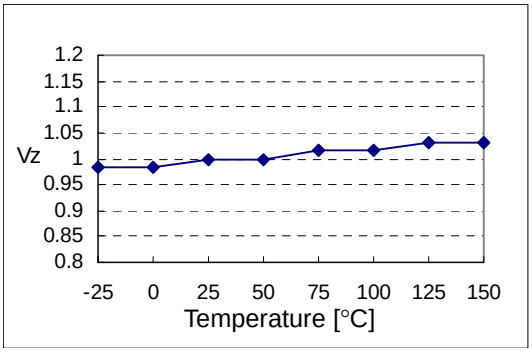


Figure 9. V_{CC} Zener Voltage

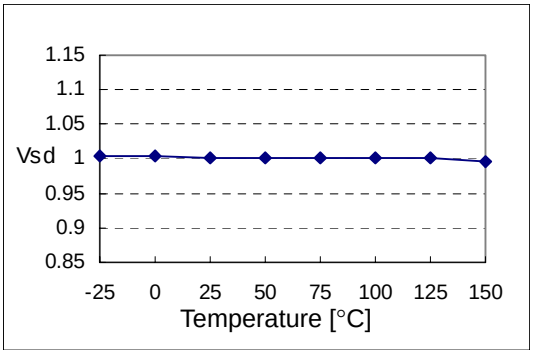


Figure 10. Shutdown Feedback Voltage

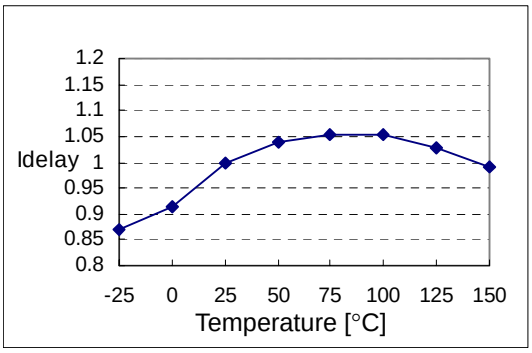


Figure 11. Shutdown Delay Current

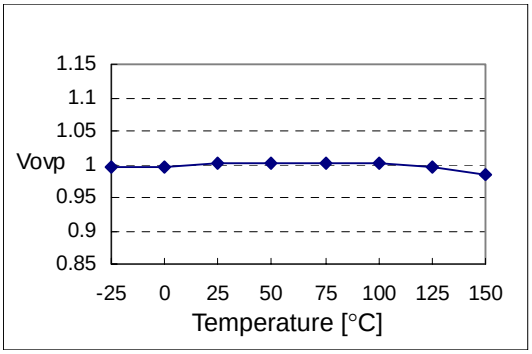


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

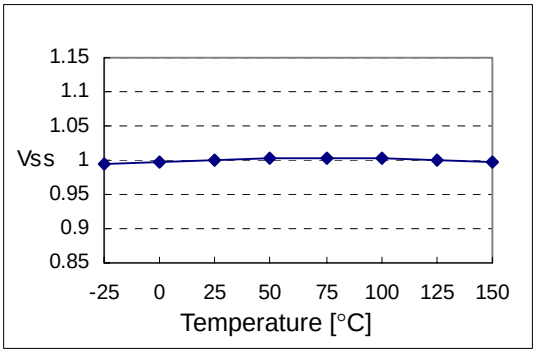


Figure13. Soft Start Voltage

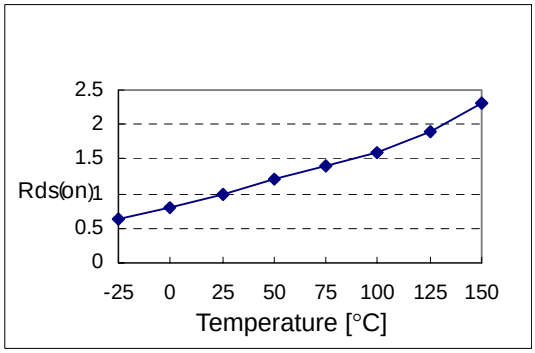
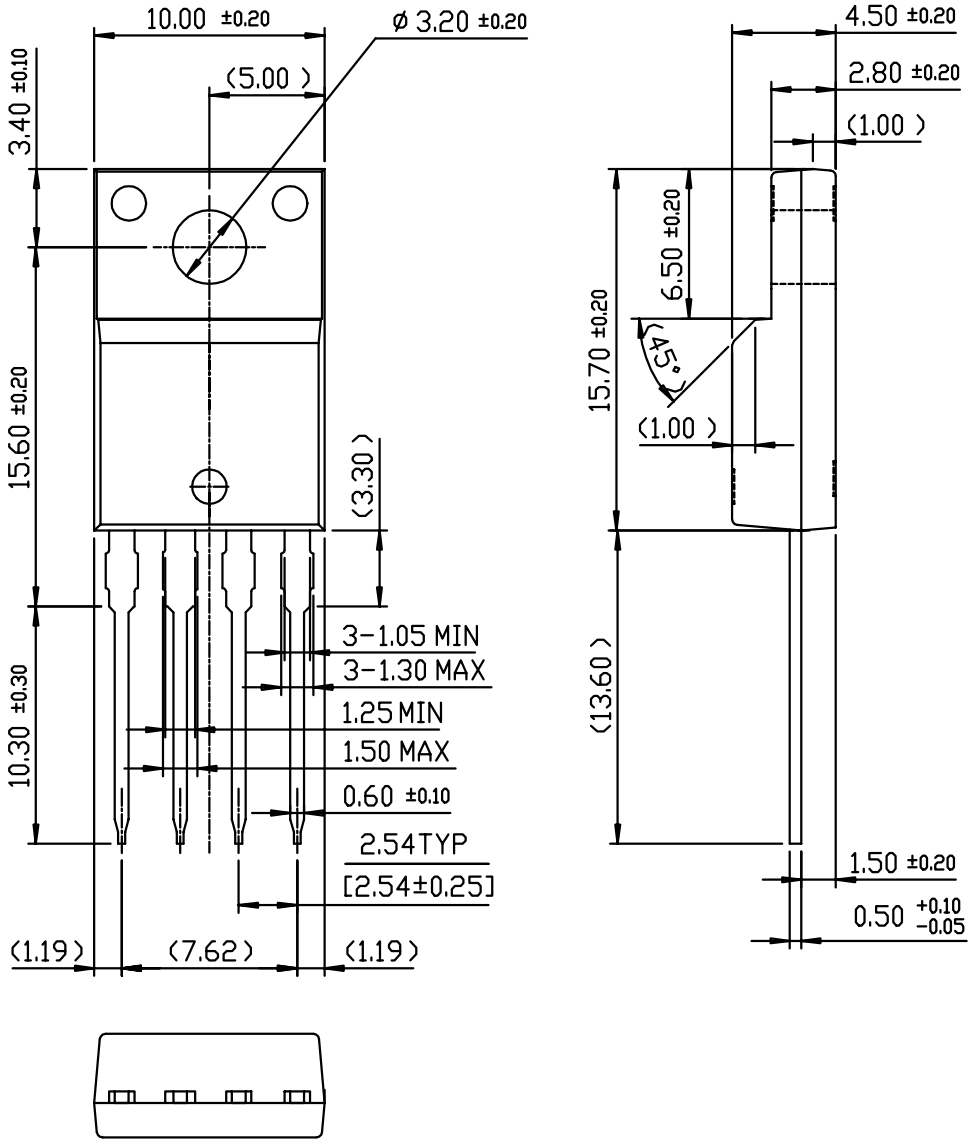


Figure 14. Static Drain-Source on Resistance

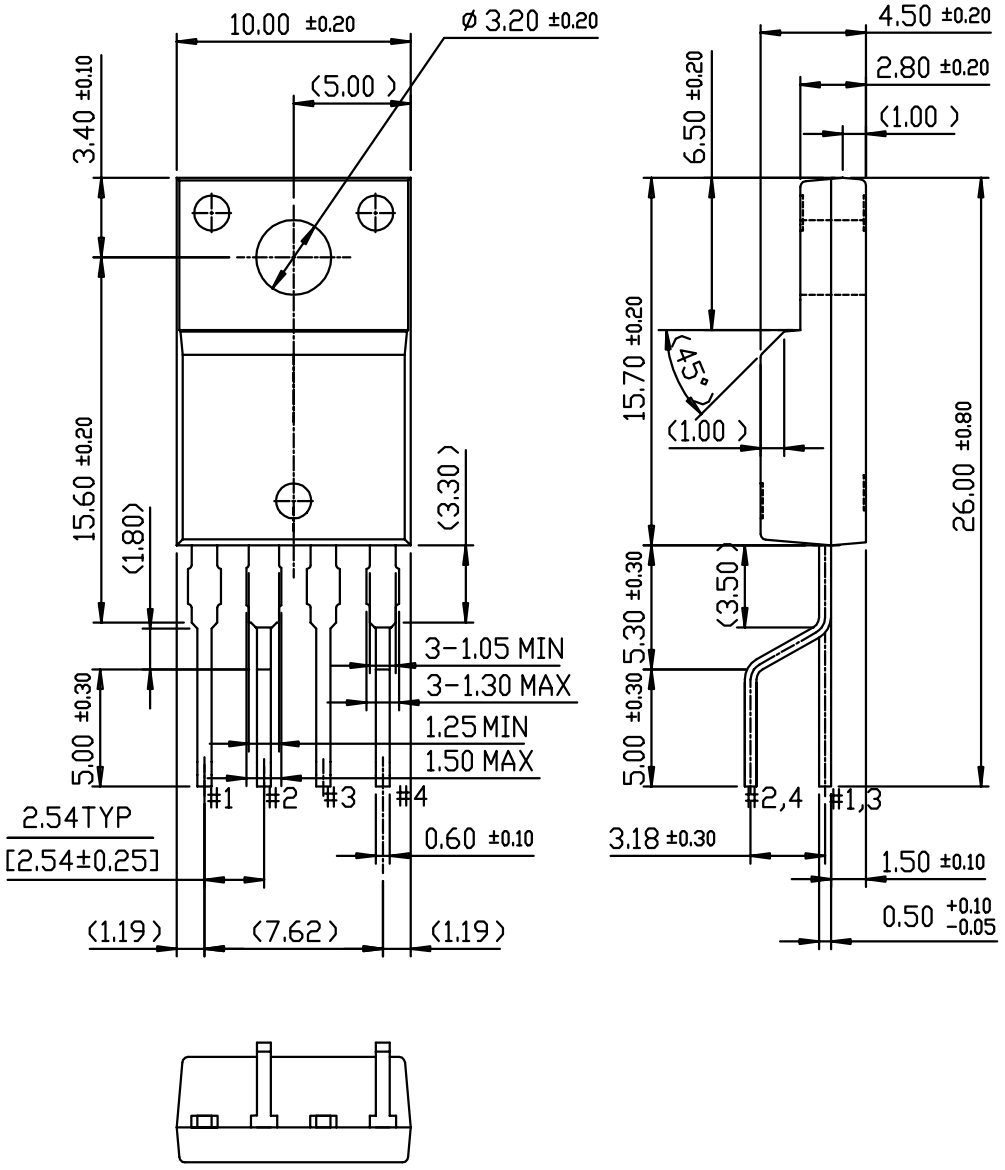
Package Dimensions

TO-220F-4L



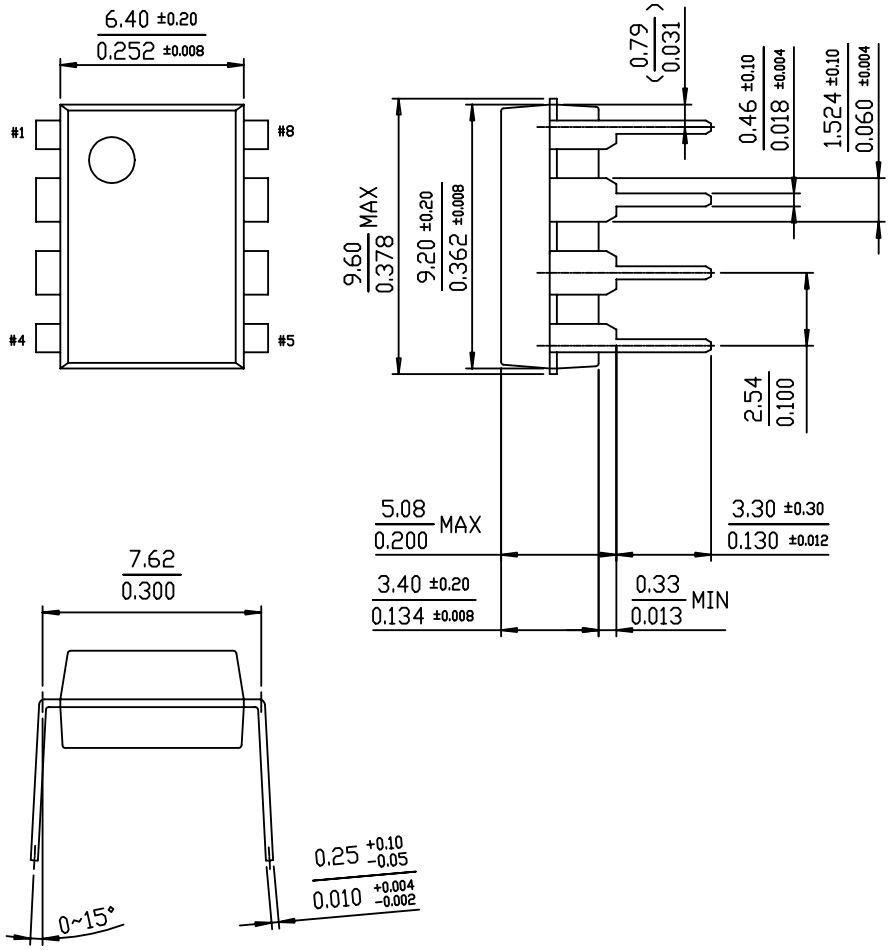
Package Dimensions (Continued)

TO-220F-4L(Forming)



Package Dimensions (Continued)

8-DIP



Ordering Information

Product Number	Package	Marking Code	BV_{DSS}	F_{OSC}	$R_{DS(on)}$
KA5H0165RTU	TO-220F-4L	5H0165R	650V	100kHz	8Ω
KA5H0165RYDTU	TO-220F-4L(Forming)				
KA5M0165RTU	TO-220F-4L	5M0165R	650V	67kHz	8Ω
KA5M0165RYDTU	TO-220F-4L(Forming)				
KA5L0165RTU	TO-220F-4L	5L0165R	650V	50kHz	8Ω
KA5L0165RYDTU	TO-220F-4L(Forming)				
KA5H0165RN	8-DIP	5H0165R	650V	100kHz	8Ω
KA5M0165RN	8-DIP	5M0165R	650V	67kHz	8Ω
KA5L0165RN	8-DIP	5L0165R	650V	50kHz	8Ω

Product Number	Package	Marking Code	BV_{DSS}	F_{OSC}	$R_{DS(on)}$
KA5H0165RVN	8-DIP	5H0165RV	650V	100kHz	8Ω

TU : Non Forming Type
YDTU : Forming Type

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